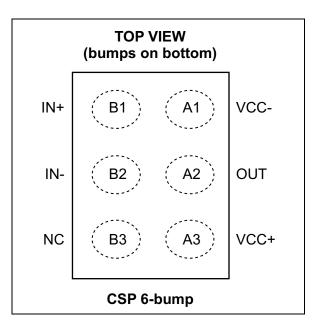


TS985

Datasheet - production data

Micropower low-voltage, 1.2 x 0.8 mm CSP comparator



Features

- Supply operation from 1.8 to 5 V
- Low current consumption: 14 μA
- Rail to rail inputs, push-pull outputs
- Low propagation delay: 300 ns
- 60 µA supply current at 1 MHz switching frequency
- Low output saturation voltage
- Internal hysteresis
- Wide temperature range: -40 ° to 85 °C
- ESD tolerance: 2 kV HBM
- 6-bump CSP, 1.2 x 0.8 mm, 400 µm pitch

Applications

- Mobiles phones
- Battery supplied electronics
- General purpose portable devices
- General purpose low voltage applications

Description

The TS985 is a single micropower and low voltage comparator. It can operate with a supply voltage ranging from 1.8 V to 5 V with a typical current consumption as low as 14 μ A while achieving a 300 ns propagation delay. In addition, rail-to-rail inputs make it a perfect choice for low voltage applications.

The 6-bump chip scale package (CSP) is a real advantage for overcoming space constraints.

TS985 is specified for temperature between -40 °C to 85 °C, making it ideal for a wide range of applications.

This is information on a product in full production.

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1 Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V _{CC}	Supply voltage ⁽¹⁾	5.5		
V _{id}	Differential input voltage ⁽²⁾	±5.5	v	
V _{in}	Input voltage ⁽³⁾	$(V_{CC}) - 0.3 \text{ to } (V_{CC}) + 0.3$	v	
V _{out}	Output voltage 5.5			
١ _F	Forward current in ESD protection diodes on inputs ⁽⁴⁾	10	mA	
Тj	Maximum junction temperature	150	°C	
T _{stg}	Storage temperature range	-65 to 150	C	
R _{thja}	Thermal resistance junction to ambient ⁽⁵⁾	ТВА	°C/W	
ESD	HBM: human body model ⁽⁶⁾	2000	V	
ESD	CDM: charged device model ⁽⁷⁾	1500	v	
	Latch-up immunity	200	mA	

Table 1	Absolute	maximum	ratings	(AMR)
	. Absolute	maximum	raungs	

1. All voltage values, except differential voltage, are with respect to network ground terminal.

2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

3. Excursions of input voltages may exceed the power supply level. As long as the common mode voltage [V_{icm}=(V_{in}⁺ + V_{in})/2] remains within the specified range, the comparator will provide a stable output state. However, the maximum current through the ESD diodes (IF) of the input stage must strictly be observed.

- 4. Guaranteed by design.
- 5. Short-circuits can cause excessive heating and destructive dissipation. Values are typical
- 6. According to JEDEC standard JESD22-A114F.
- 7. According to ANSI/ESD STM5.3.1.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V _{CC} ⁺	Supply voltage	1.8 to 5.0	
V.	Common mode input voltage range, T _{amb} = 25 °C	(V_{CC}^{-}) - 0.25 to (V_{CC}^{+}) + 0.25	V
V _{icm}	Common mode input voltage range, T _{min} ≤T _{amb} ≤T _{max}	(V_{CC}) to (V_{CC})	
T _{oper}	Operating free-air temperature range	-40 to 85	°C



2 Electrical characteristics

Symbol	Parameter	Min.	Тур.	Max.	Unit
V	Input offset voltage, full V _{icm} range		0.5	8	m\/
V _{io}	Input offset voltage, T _{min} ≤T _{amb} ≤T _{max}			9	— mV
$\Delta V_{io} / \Delta T$	Input offset voltage drift vs. temperature		4.5		uV/°C
V _{Hyst}	Input hysteresis voltage		3		mV
L.	Input bias current ⁽¹⁾ , full V _{icm} range		14	40	
l _{ib}	Input bias current ⁽¹⁾ , $T_{min} \le T_{amb} \le T_{max}$			100	nA
	Input offset current, full V _{icm} range		1	10	
l _{io}	Input offset current, $T_{min} \le T_{amb} \le T_{max}$			100	
CMR	Common-mode rejection ratio, V_{icm} = 0 to 1.8 V	43			dB
l	Supply current per comparator, no load - V_{icm} = 0 V		13	19	μΑ
I _{CC}	Supply current per comparator, $T_{min} \le T_{amb} \le T_{max}$			20	μΑ
M	High-level output voltage, I _{Source} = 1 mA	1.69	1.71		v
V _{OH}	High-level output voltage, $T_{min} \le T_{amb} \le T_{max}$	1.67			v
V _{OL}	Low-level output voltage, I _{Sink} = 1 mA		65	80	mV
VOL	Low-level output voltage, $T_{min} \le T_{amb} \le T_{max}$			95	IIIV
	V _{OUT} = 0 V	6	8		
I _{Sink}	$T_{min} \le T_{amb} \le T_{max}$	5			mA
1-	$V_{OUT} = V_{CC}$	4.5	7.3		
I _{Source}	$T_{min} \le T_{amb} \le T_{max}$	3.5			
+	Response time high to low $^{(2)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 10 mV		730		
t _{PHL}	Response time high to low $^{(2)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 100 mV	igh to low $^{(2)}$, $V_{icm} = 0$ V, $C_L = 15$ pF, 300			
+	Response time low to high $^{(3)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 10 mV		730		– ns
t _{PLH}	Response time low to high $^{(3)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 100 mV		300		

1. Maximum values include unavoidable inaccuracies of the industrial tests.

2. TP_{HL} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: inverting input voltage (IN-) = V_{ICM} and non-inverting input (IN+), moving from V_{ICM} + 100mV to V_{ICM} - overdrive.

3. TP_{LH} is measured when the output signal crosses a voltage level at 50 % of V_{CC} with the following conditions: inverting input voltage (IN-) = V_{ICM} and non-inverting input (IN+), moving from V_{ICM} - 100 mV to V_{ICM} + overdrive.



Symbol	Parameter	Min.	Тур.	Max.	Unit	
V	Input offset voltage, full V _{icm} range		0.5	8	m\/	
V _{io}	Input offset voltage, T _{min} ≤T _{amb} ≤T _{max}			9	— mV	
$\Delta V_{io} / \Delta T$	Input offset voltage drift vs. temperature		4.5		uV/°C	
V _{Hyst}	Input hysteresis voltage		3		mV	
I	Input bias current ⁽¹⁾ , full V _{icm} range		15	40		
I _{ib}	Input bias current ⁽¹⁾ , $T_{min} \le T_{amb} \le T_{max}$			100	n ^	
	Input offset current, full V _{icm} range		1	10	– nA	
I _{io}	Input offset current, $T_{min} \le T_{amb} \le T_{max}$			100		
CMR	Common-mode rejection ratio, V _{icm} = 0 to 2.7 V	48			dB	
1	Supply current per comparator, no load - V _{icm} = 0 V		14	20		
I _{CC}	Supply current per comparator, $T_{min} \le T_{amb} \le T_{max}$			22	μΑ	
V	High-level output voltage, I _{Source} = 1 mA	2.6	2.64		V	
V _{OH}	High-level output voltage, $T_{min} \le T_{amb} \le T_{max}$	2.5			V	
V	Low-level output voltage, I _{Sink} = 1 mA		43	55	mV	
V _{OL}	Low-level output voltage, $T_{min} \le T_{amb} \le T_{max}$			65	IIIV	
	V _{OUT} = 0 V	14	18			
I _{Sink}	$T_{min} \le T_{amb} \le T_{max}$	12			mA	
L	V _{OUT} = V _{CC}	14	18			
I _{Source}	$T_{min} \le T_{amb} \le T_{max}$	12				
÷	Response time high to low $^{(2)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 10 mV		860			
t _{PHL}	Response time high to low $^{(2)}$, $V_{icm} = 0 V$, $C_L = 15 pF$, overdrive = 100 mV 330					
4	Response time low to high $^{(3)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 10 mV		860		— ns	
t _{PLH}	Response time low to high $^{(3)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 100 mV		330			

Table 4. V_{CC}⁺ = 2.7 V, V_{CC}⁻ = 0 V, T_{amb} = 25 °C (unless otherwise specified)

1. Maximum values include unavoidable inaccuracies of the industrial tests.

2. TP_{HL} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: inverting input voltage (IN-) = V_{ICM} and non-inverting input (IN+), moving from V_{ICM} + 100mV to V_{ICM} - overdrive.

3. TP_{LH} is measured when the output signal crosses a voltage level at 50 % of V_{CC} with the following conditions: inverting input voltage (IN-) = V_{ICM} and non-inverting input (IN+), moving from V_{ICM} - 100 mV to V_{ICM} + overdrive.



Symbol	Parameter	Min.	Тур.	Max.	Unit
V	Input offset voltage, full V _{icm} range		0.5	8	m\/
V _{io}	Input offset voltage, T _{min} ≤T _{amb} ≤T _{max}			9	— mV
$\Delta V_{io} / \Delta T$	Input offset voltage drift vs. temperature		4.5		uV/°C
V _{Hyst}	Input hysteresis voltage		3		mV
1	Input bias current ⁽¹⁾ , full V _{icm} range		17	50	
l _{ib}	Input bias current ⁽¹⁾ , $T_{min} \le T_{amb} \le T_{max}$ 10		100	nA	
	Input offset current, full V _{icm} range 1 10		10		
I _{io}	Input offset current, $T_{min} \le T_{amb} \le T_{max}$			100	
CMR	Common-mode rejection ratio, V _{icm} = 0 to 5 V	56			dB
1	Supply current per comparator, no load - V _{icm} = 0 V		16	24	
I _{CC}	Supply current per comparator, $T_{min} \le T_{amb} \le T_{max}$			25	μΑ
V	High-level output voltage, I _{Source} = 1 mA4.854.9			V	
V _{OH}	High-level output voltage, $T_{min} \le T_{amb} \le T_{max}$	4.8			v
V	Low-level output voltage, I _{Sink} = 1 mA		31	45	mV
V _{OL}	Low-level output voltage, $T_{min} \le T_{amb} \le T_{max}$			55	IIIV
	V _{OUT} = 0 V	35	42		
I _{Sink}	$T_{min} \le T_{amb} \le T_{max}$	30			^
1	V _{OUT} = V _{CC}	45	52		— mA
I _{Source}	$T_{min} \le T_{amb} \le T_{max}$	40			
+	Response time high to low $^{(2)}$, $V_{icm} = 0 V$, $C_L = 15 pF$, overdrive = 10 mV1100				
t _{PHL}	Response time high to low $^{(2)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 100 mV		420		
4	Response time low to high $^{(3)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 10 mV		1100		– ns
t _{PLH}	Response time low to high $^{(3)}$, V _{icm} = 0 V, C _L = 15 pF, overdrive = 100 mV		420		

Table 5. V_{CC}^+ = 5 V, V_{CC}^- = 0 V, T_{amb} = 25 °C (unless otherwise specified)

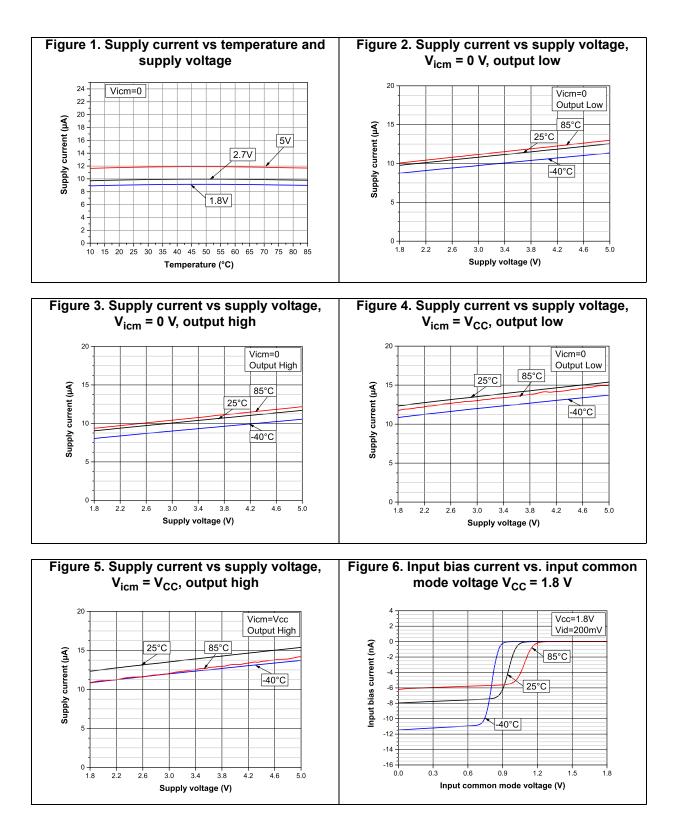
1. Maximum values include unavoidable inaccuracies of the industrial tests.

2. TP_{HL} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: inverting input voltage (IN-) = V_{ICM} and non-inverting input (IN+), moving from V_{ICM} + 100mV to V_{ICM} - overdrive.

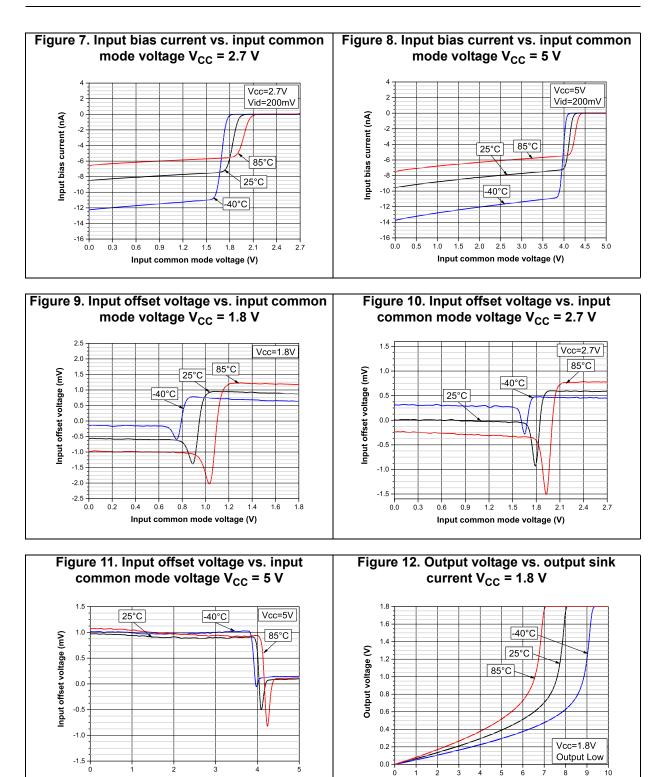
3. TP_{LH} is measured when the output signal crosses a voltage level at 50 % of V_{CC} with the following conditions: inverting input voltage (IN-) = V_{ICM} and non-inverting input (IN+), moving from V_{ICM} - 100 mV to V_{ICM} + overdrive.



3 Electrical characteristic curves



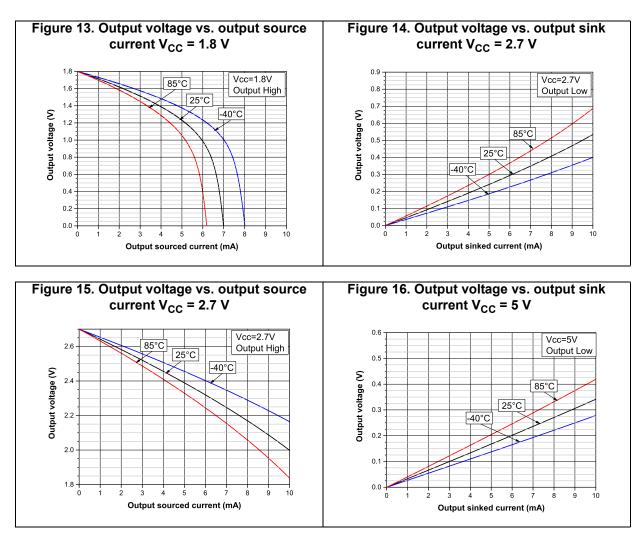


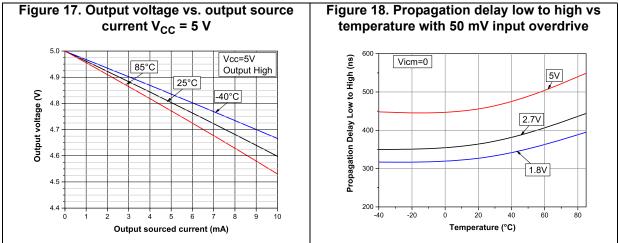


Input common mode voltage (V)



Output sinked current (mA)







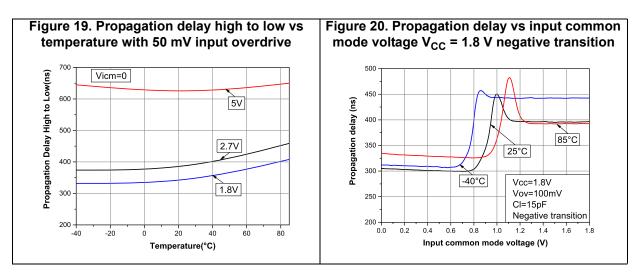


Figure 21. Propagation delay vs input common
mode voltage V_{CC} = 1.8 V positive transitionFigure 22. Propagation delay vs input common
mode voltage V_{CC} = 2.7 V negative transition

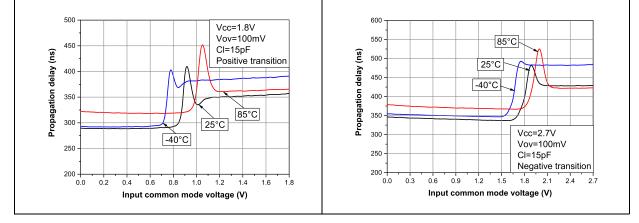
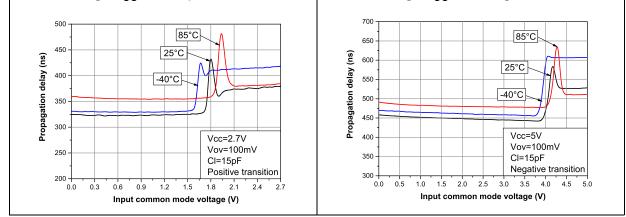


Figure 23. Propagation delay vs input common
mode voltage V_{CC} = 2.7 V positive transitionFigure 24. Propagation delay vs input common
mode voltage V_{CC} = 5 V negative transition



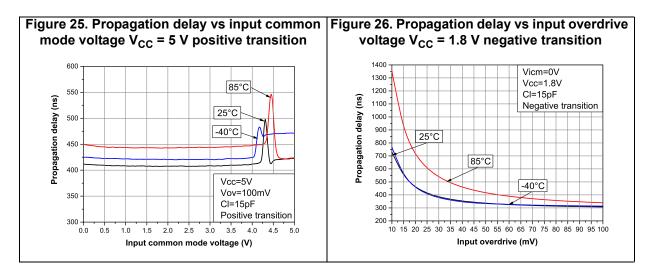


Figure 27. Propagation delay vs input overdrive
voltage V_{CC} = 1.8 V positive transitionFigure 28. Propagation delay vs input overdrive
voltage V_{CC} = 2.7 V negative transition

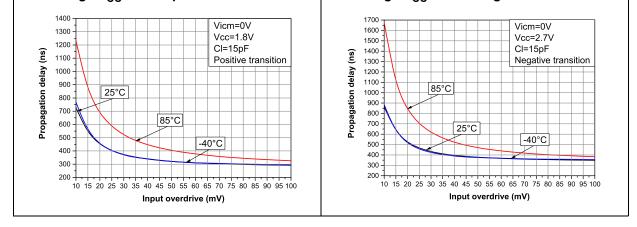
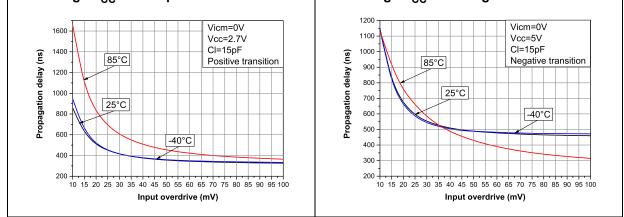
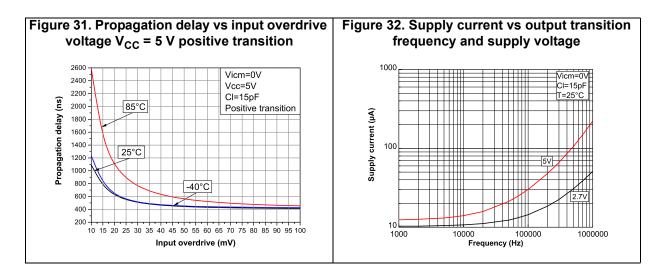


Figure 29. Propagation delay vs input overdrive
voltage V_{CC} = 2.7 V positive transitionFigure 30. Propagation delay vs input overdrive
voltage V_{CC} = 5 V negative transition







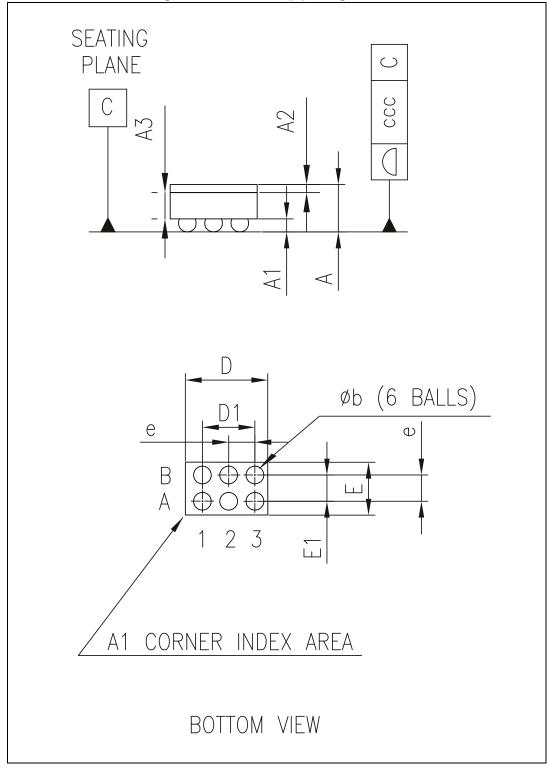
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4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



Figure 33. CSP 6-bump package outline



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	1		o-builth life				
			Dime	nsions			
Ref.		Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	0.485	0.525	0.57	0.019	0.021	0.022	
A1	0.17		0.23	0.007		0.009	
A2		0.025	0.03		0.001	0.001	
A3	0.275	0.3	0.325	0.011	0.012	0.013	
b	0.23	0.26	0.29	0.009	0.01	0.011	
D	1.18	1.2	1.22	0.046	0.047	0.048	
D1		0.8			0.031		
E	0.78	0.8	0.82	0.031	0.031	0.032	
E1		0.4			0.016		
е		0.4			0.016		
CCC			0.075			0.003	

Table 6. CSP 6-bump mechanical data



5 Ordering information

Table	7.	Order	codes
-------	----	-------	-------

Order code	Temperature range	Package	Packing	Marking
TS985IJT	-40 °C to 85 °C	CSP 6-bump	Tape and reel	TBA



6 Revision history

Table 8. Document revision history

Date	Revision	Changes
23-Jun-2016	1	Initial release



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